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Bis(dimethyl sulfoxide- κO)bis(mercaptoacetato- $\kappa^2 O$,S)tin(IV)

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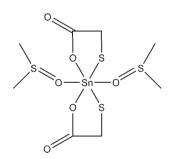
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Key indicators: single-crystal X-ray study; T = 130 K; mean σ (C–C) = 0.003 Å; R factor = 0.020; wR factor = 0.047; data-to-parameter ratio = 20.7.

In the title compound, $[Sn(C_2H_2O_2S)_2(C_2H_6OS)_2]$, the mercaptoacetato ligands chelate to Sn^{IV} through S and one O atoms. The metal centre is also coordinated by two dimethyl sulfoxide (DMSO) ligands through the O atom, leading to an overall distorted octahedral coordination environment for the Sn^{IV} atom. The molecular adduct lies on a twofold rotation axis.

Related literature

For related structures of tin-mercaptoacetates, see: Holmes *et al.* (1988); Song *et al.* (1998); Ng *et al.* (1996); Zhang *et al.* (2006); Song *et al.* (2005); Wu *et al.* (2000); Zhong *et al.* (2004*a*,*b*, 2005*a*,*b*). For the chemistry of tin compounds, see: Smith (1998).



Experimental

Crystal data

 $[Sn(C_2H_2O_2S)_2(C_2H_6OS)_2]$ $M_r = 455.14$ Monoclinic, C2/c a = 13.3460 (17) Å b = 8.2706 (7) Å c = 14.9053 (18) Å $\beta = 107.124$ (5)° $V = 1572.3 (3) Å^{3}$ Z = 4Mo Ka radiation $\mu = 2.17 \text{ mm}^{-1}$ T = 130 K $0.20 \times 0.15 \times 0.15 \text{ mm}$

Data collection

Rigaku R-AXIS RAPID

diffractometer Absorption correction: multi-scan (*ABSCOR*; Higashi, 1995) $T_{min} = 0.671, T_{max} = 0.737$

Refinement

 $R[F^2 > 2\sigma(F^2)] = 0.020$ $wR(F^2) = 0.047$ S = 1.101800 reflections 5801 measured reflections 1800 independent reflections 1718 reflections with $I > 2\sigma(I)$ $R_{\text{int}} = 0.021$

87 parameters H-atom parameters constrained $\Delta \rho_{max} = 0.75$ e Å⁻³ $\Delta \rho_{min} = -0.43$ e Å⁻³

Data collection: *PROCESS-AUTO* (Rigaku, 1998); cell refinement: *PROCESS-AUTO*; data reduction: *CrystalStructure* (Rigaku/ MSC, 2004); program(s) used to solve structure: *SHELXS97* (Sheldrick, 2008); program(s) used to refine structure: *SHELXL97* (Sheldrick, 2008); molecular graphics: *SHELXTL* (Sheldrick, 2008); software used to prepare material for publication: *SHELXTL*.

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Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: NG2673).

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supporting information

Acta Cryst. (2009). E65, m1450 [https://doi.org/10.1107/S160053680904361X] Bis(dimethyl sulfoxide-κO)bis(mercaptoacetato-κ²O,S)tin(IV)

Li Song

S1. Comment

Compared with organotin compounds, inorganic compounds of tin are also important in industry applications, for example, electroplating, ceramic glazes and pigments, heterogeneous catalysts, gas sensors, and so on. (Smith *et al.*, 1998) Perhaps the most important recent development in tin (iv) chemistry has been the increase in studies of the solid state properties of tin (iv) compounds. Sn(SCH₂CH₂S)₂ could act as a typical Lewis acid and reveal to be a electron acceptor. And many structures have been reported to exhibit the reaction of Sn(SCH₂CH₂S)₂ and ligands. (Wu *et al.*, 2000; Holmes *et al.*, 1988) Here, the S-contained chelated ligand is mercapto acetic acid but not 1,2-ethanedithiol ligand, and the solvent DMSO act as the second ligand.

The title compound, $Sn(C_2H_2O_2S)_2(DMSO)_2$, is a mononuclear structure and crystallizes in monoclinic form in the space group C2/c. As shown in Figure 1, the asymmetric unit is composed of half tin atom, one mercaptoacetato and one DMSO ligand. According to a C2 symmetry axis pass the tin (iv) site, a mononuclear structure is present. In which, two mercaptoacetato ligands coordinates to Sn^{IV} through S and one O atoms. The metal centre is also coordinated by two dimethyl sulfoxide ligands through O atom, froming a SnO_4S_2 distorted octahedronal coordinated sphere. Around the metal centre, two mercaptoacetato ligands adopt *cis* chelated mode to form a SnO_2S_2 distorted equatorial plan. And other two DMSO ligands join on it from two polars of the coordinated sphere, also with *cis* mode around the metal centre.

S2. Experimental

All chemicals were obtained from commercial sources and were used as received. The title compound was handily synthesized by a solution reaction from mercapto acetic acid. HSCH₂COOH (56 mg, 0.6 mmol) and NaOH (50 mg, 1.2 mmol) was dissolved in 10 ml of water. To this solution was added a 5 ml aqueous solution of SnCl₄.5H₂O (106 mg, 0.3 mmol) at room temperature. Amount of white precipitates were gradually formed and colected by filtrating and washing with water. Then they were dissolved in 5 ml DMSO and the filtration was slowly evaperated at room temperature. After several days, a great deal of colorless crystals were obtained, yield about 113 mg (83% on tin).

S3. Refinement

The structure was solved using direct methods and refined by full-matrix least-squares techniques. All non-hydrogen atoms were assigned anisotropic displacement parameters in the refinement. All hydrogen atoms were added at calculated positions and refined using a riding model. The structure was refined on F2 using *SHELXTL97* software package(Sheldrick *et al.*, 2008) without any unusual events.

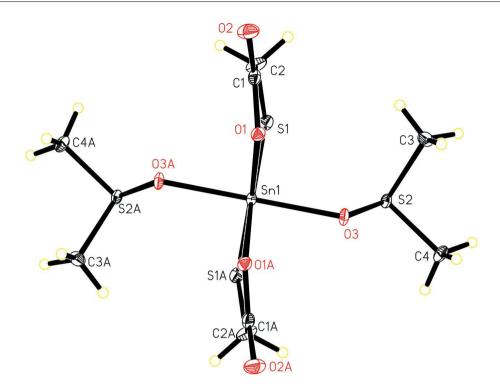


Figure 1

Structure and labeling of the title compound, with displacement ellipsoids drawn at the 30% probability level and H atoms shown as small spheres of arbitrary radii.

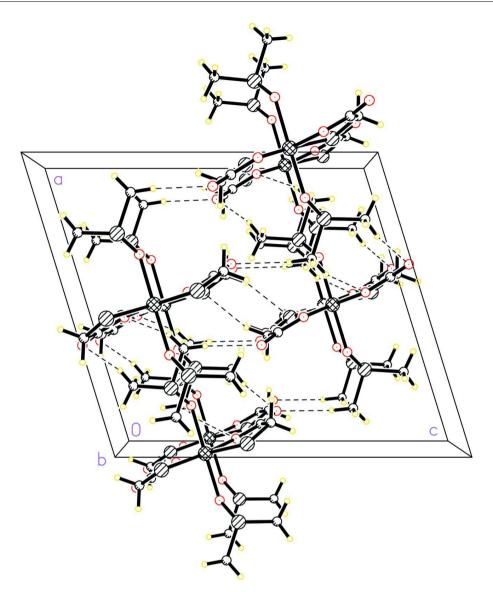


Figure 2

The packing diagram viewed along the b-direction.

Bis(dimethyl sulfoxide- κO)bis(mercaptoacetato- $\kappa^2 O$,S)tin(IV)

Crystal data

 $[Sn(C_2H_2O_2S)_2(C_2H_6OS)_2]$ $M_r = 455.14$ Monoclinic, C2/c Hall symbol: -C 2yc a = 13.3460 (17) Å b = 8.2706 (7) Å c = 14.9053 (18) Å $\beta = 107.124 (5)^{\circ}$ $V = 1572.3 (3) \text{ Å}^3$ Z = 4 F(000) = 904 $D_x = 1.923 \text{ Mg m}^{-3}$ Mo K α radiation, $\lambda = 0.71075 \text{ Å}$ Cell parameters from 2229 reflections $\theta = 3.1-27.5^{\circ}$ $\mu = 2.17 \text{ mm}^{-1}$ T = 130 KPrism, white $0.20 \times 0.15 \times 0.15 \text{ mm}$ Data collection

Dura concerión	
Rigaku R-AXIS RAPID diffractometer	5801 measured reflections 1800 independent reflections
Radiation source: fine-focus sealed tube	1718 reflections with $I > 2\sigma(I)$
Graphite monochromator	$R_{\rm int} = 0.021$
Detector resolution: 14.6306 pixels mm ⁻¹	$\theta_{\rm max} = 27.5^{\circ}, \theta_{\rm min} = 3.2^{\circ}$
CCD_Profile_fitting scans	$h = -11 \rightarrow 17$
Absorption correction: multi-scan	$k = -10 \rightarrow 10$
(ABSCOR; Higashi, 1995)	$l = -19 \rightarrow 19$
$T_{\min} = 0.671, \ T_{\max} = 0.737$	
Refinement	
Refinement on F^2	Secondary atom site location: difference Fourier
Least-squares matrix: full	map
$R[F^2 > 2\sigma(F^2)] = 0.020$	Hydrogen site location: inferred from
$wR(F^2) = 0.047$	neighbouring sites
S = 1.10	H-atom parameters constrained
1800 reflections	$w = 1/[\sigma^2(F_o^2) + (0.0207P)^2 + 2.5592P]$
87 parameters	where $P = (F_o^2 + 2F_c^2)/3$
0 restraints	$(\Delta/\sigma)_{\rm max} = 0.001$
Primary atom site location: structure-invariant	$\Delta ho_{ m max} = 0.75 \ { m e} \ { m \AA}^{-3}$
direct methods	$\Delta \rho_{\rm min} = -0.43 \text{ e} \text{ Å}^{-3}$

Special details

Geometry. All e.s.d.'s (except the e.s.d. in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell e.s.d.'s are taken into account individually in the estimation of e.s.d.'s in distances, angles and torsion angles; correlations between e.s.d.'s in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell e.s.d.'s is used for estimating e.s.d.'s involving l.s. planes.

Refinement. Refinement of F^2 against ALL reflections. The weighted *R*-factor *wR* and goodness of fit *S* are based on F^2 , conventional *R*-factors *R* are based on *F*, with *F* set to zero for negative F^2 . The threshold expression of $F^2 > \sigma(F^2)$ is used only for calculating *R*-factors(gt) *etc.* and is not relevant to the choice of reflections for refinement. *R*-factors based on F^2 are statistically about twice as large as those based on *F*, and *R*- factors based on ALL data will be even larger.

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters $(Å^2)$

	x	У	Z	$U_{ m iso}$ */ $U_{ m eq}$
Sn1	0.0000	0.20692 (2)	0.7500	0.01316 (7)
S1	-0.04306 (4)	0.02254 (7)	0.61815 (4)	0.02162 (12)
S2	0.22228 (4)	0.12036 (6)	0.71261 (3)	0.01444 (11)
01	-0.04086 (11)	0.39054 (17)	0.65158 (10)	0.0164 (3)
O2	-0.13288 (14)	0.4586 (2)	0.50766 (10)	0.0285 (4)
03	0.16014 (11)	0.24764 (18)	0.75112 (10)	0.0179 (3)
C1	-0.09221 (16)	0.3555 (3)	0.56564 (14)	0.0194 (4)
C2	-0.1050 (2)	0.1784 (3)	0.53429 (16)	0.0296 (5)
H2B	-0.0781	0.1677	0.4794	0.036*
H2A	-0.1811	0.1547	0.5122	0.036*
C3	0.22763 (19)	0.2033 (3)	0.60389 (15)	0.0239 (5)
H3A	0.1588	0.1928	0.5571	0.036*
H3B	0.2801	0.1449	0.5823	0.036*
H3C	0.2469	0.3178	0.6124	0.036*
C4	0.35322 (16)	0.1546 (3)	0.78190 (16)	0.0215 (4)
H4A	0.3626	0.1143	0.8457	0.032*

supporting information

H4B	0.3682	0.2708	0.7842	0.032*
H4C	0.4013	0.0978	0.7542	0.032*

 U^{11} U^{22} U^{33} U^{12} U^{13} U^{23} 0.01662 (10) 0.00996 (10) 0.000 0.00506(7) 0.000 Sn1 0.01364 (11) **S**1 0.0191 (3) 0.0178 (3) 0.0260 (3) 0.0000(2) 0.0035 (2) -0.0068(2)S2 0.0111 (2) 0.0132 (2) 0.0194 (2) 0.00096 (18) 0.00510 (19) -0.00037(17)01 0.0143 (7) 0.0163 (7) 0.0177 (6) -0.0018 (6) 0.0033 (6) 0.0011 (5) O2 0.0319 (9) 0.0303 (9) 0.0192 (7) 0.0098 (7) 0.0013 (7) 0.0025 (7) O3 0.0106(7) 0.0193 (7) 0.0259(7) -0.0017(6)0.0086 (6) -0.0053(6)C1 0.0063 (8) 0.0132 (10) 0.0253 (11) 0.0206 (10) 0.0041 (8) -0.0018(8)C2 0.0264 (12) 0.0304 (13) 0.0231 (11) 0.0113 (10) -0.0065 (10) -0.0076(9)C3 0.0250(12) 0.0303 (12) 0.0180 (9) 0.0026 (9) 0.0088 (9) 0.0008 (9) C4 0.0117 (10) 0.0217 (10) 0.0280(11) 0.0037 (8) 0.0013 (9) -0.0023(9)

Atomic displacement parameters (Å	²)
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Geometric parameters (Å, °)

Sn1—O1 ⁱ	2.0699 (14)	O2—C1	1.222 (3)	
Sn1—O1	2.0699 (14)	C1—C2	1.531 (3)	
Sn1—O3	2.1587 (14)	C2—H2B	0.9900	
Sn1—O3 ⁱ	2.1587 (14)	C2—H2A	0.9900	
Sn1—S1	2.4193 (6)	С3—НЗА	0.9800	
$Sn1$ — $S1^i$	2.4193 (6)	C3—H3B	0.9800	
S1—C2	1.817 (2)	С3—НЗС	0.9800	
S2—O3	1.5511 (15)	C4—H4A	0.9800	
S2—C4	1.771 (2)	C4—H4B	0.9800	
S2—C3	1.780 (2)	C4—H4C	0.9800	
01—C1	1.295 (2)			
Ol ⁱ —Snl—Ol	85.61 (8)	O2—C1—O1	122.6 (2)	
O1 ⁱ —Sn1—O3	80.01 (6)	O2—C1—C2	117.72 (19)	
O1—Sn1—O3	86.83 (6)	O1—C1—C2	119.67 (19)	
O1 ⁱ —Sn1—O3 ⁱ	86.83 (6)	C1—C2—S1	118.77 (16)	
O1—Sn1—O3 ⁱ	80.01 (6)	C1—C2—H2B	107.6	
O3—Sn1—O3 ⁱ	162.05 (8)	S1—C2—H2B	107.6	
Ol ⁱ —Snl—Sl	171.18 (4)	C1—C2—H2A	107.6	
O1—Sn1—S1	86.38 (4)	S1—C2—H2A	107.6	
O3—Sn1—S1	95.88 (4)	H2B—C2—H2A	107.1	
O3 ⁱ —Sn1—S1	95.41 (4)	S2—C3—H3A	109.5	
$O1^{i}$ — $Sn1$ — $S1^{i}$	86.38 (4)	S2—C3—H3B	109.5	
O1—Sn1—S1 ⁱ	171.18 (4)	НЗА—СЗ—НЗВ	109.5	
$O3$ — $Sn1$ — $S1^i$	95.41 (4)	S2—C3—H3C	109.5	
$O3^i$ — $Sn1$ — $S1^i$	95.88 (4)	НЗА—СЗ—НЗС	109.5	
$S1$ — $Sn1$ — $S1^i$	101.85 (3)	НЗВ—СЗ—НЗС	109.5	
C2—S1—Sn1	93.60 (8)	S2—C4—H4A	109.5	
O3—S2—C4	102.64 (9)	S2—C4—H4B	109.5	

O3—S2—C3	104.15 (10)	H4A—C4—H4B	109.5
C4—S2—C3	99.90 (11)	S2—C4—H4C	109.5
C1—O1—Sn1	119.26 (14)	H4A—C4—H4C	109.5
S2—O3—Sn1	121.82 (8)	H4B—C4—H4C	109.5
$O1^{i}$ —Sn1—S1—C2	-36.3 (3)	C3—S2—O3—Sn1	106.14 (12)
O1—Sn1—S1—C2	-11.53 (10)	O1 ⁱ —Sn1—O3—S2	161.54 (11)
O3—Sn1—S1—C2	-97.96 (10)	O1—Sn1—O3—S2	-112.37 (10)
$O3^{i}$ —Sn1—S1—C2	68.06 (10)	O3 ⁱ —Sn1—O3—S2	-155.05 (10)
S1 ⁱ —Sn1—S1—C2	165.24 (9)	S1—Sn1—O3—S2	-26.35 (10)
O1 ⁱ —Sn1—O1—C1	-169.37 (17)	S1 ⁱ —Sn1—O3—S2	76.19 (10)
O3—Sn1—O1—C1	110.43 (15)	Sn1—O1—C1—O2	168.26 (17)
O3 ⁱ —Sn1—O1—C1	-81.82 (15)	Sn1—O1—C1—C2	-10.7 (3)
S1—Sn1—O1—C1	14.32 (14)	O2—C1—C2—S1	178.66 (18)
S1 ⁱ —Sn1—O1—C1	-144.6 (2)	O1—C1—C2—S1	-2.3 (3)
C4—S2—O3—Sn1	-150.07 (11)	Sn1—S1—C2—C1	10.8 (2)

Symmetry code: (i) -x, y, -z+3/2.